

Rev. V3

#### **Features**

Wideband Performance

Gain: 21 dB @ 3 GHz

• P1dB: 20 dBm @ 3 GHz

Noise Figure: 1.4 dB @ 3 GHz

OIP3: 36 dBm @ 3 GHz

Bias Voltage: 5 VBias Current: 90 mA

50 Ω Matched Input / Output

Positive Voltage Only

• Die Size: 0.59 x 0.70 mm

RoHS\* Compliant

#### **Applications**

Instrumentation & Communication Systems

#### Description

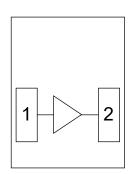
MAAM-011326-DIE is an easy-to-use, wideband amplifier that operates from 0.4 to 6 GHz. The amplifier provides 21 dB gain, 20 dBm output P1dB and 36 dBm OIP3 at 3 GHz. The gain slope is only  $\pm$  0.5 dB from 0.5 to 3 GHz. It is matched to 50  $\Omega$  with typical return losses of 15 dB at the input and 13 dB at the output. The amplifier requires only positive bias voltages and consumes 90 mA from a 5 V supply.

MAAM-011326-DIE is suitable for a wide range of applications in instrumentation and communication systems.

## **Ordering Information**

Part Number	Package
MAAM-011326-DIE	Bare Die

#### **Functional Schematic**



## Pad Configuration<sup>1,2,3</sup>

Pin#	Pin Name	Function	
1	RFIN	RF Input	
2	RFOUT / V <sub>DD</sub>	RF Output / V <sub>DD</sub>	

- 1. The RFIN pad is DC coupled and matched to 50  $\Omega$ . An external DC block is required
- 2. The RFOUT pad is DC coupled and matched to 50  $\Omega$ . DC bias is supplied through this pad.
- Backside of die must be connected to RF, DC and thermal ground.

<sup>\*</sup> Restrictions on Hazardous Substances, compliant to current RoHS EU directive.



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# Electrical Specifications: $T_B = 25^{\circ}C^4$ , $V_{DD} = +5 \text{ V}^5$ , $Z_0 = 50 \Omega$ (Probe Data with Bias Tees)

Parameter	Test Conditions	Units	Min.	Тур.	Max.
Gain	0.5 GHz 2 GHz 3 GHz 4 GHz 6 GHz	dB	21.0 — 20.0 — 19.0	22.0 21.5 21.0 21.0 20.0	_
Gain Variation vs. Temp	0.5 - 3 GHz 3 - 6 GHz	dB/°C	_	0.01 0.02	_
Gain Variation vs. Freq	0.5 - 3 GHz	dB	_	<u>+</u> 0.5	_
Noise Figure	0.5 GHz 3 GHz 6 GHz	dB	_	1.5 1.4 2.0	1.8 1.6 2.2
Input Return Loss	0.5 - 2 GHz 2 - 4 GHz 4 - 6 GHz	dB	_	-15 -16 -20	-10 -11 -10
Output Return Loss	0.5 - 6 GHz	dB	_	-13	-12
P1dB	0.5 GHz 2 GHz 3 GHz 4 GHz 5 GHz 6 GHz	dBm	_	20.3 20.3 20.0 19.0 17.6 16.2	_
Saturated Output Power	0.5 - 6 GHz	dBm	_	21	_
Output IP3 <sup>6</sup>	0.5 GHz 2 GHz 3 GHz 4 GHz 5 GHz 6 GHz	dBm	33.0 — 32.5 — — 27.5	35.0 38.0 36.0 34.0 31.5 30.0	_
Supply Current	Quiescent bias	mA	_	90	100

<sup>4.</sup> Baseplate temperature.

 <sup>5.</sup> Drain voltage injected through the RF output port using an external bias tees. Voltage at the output pin is ≈ +4.8 V.
 6. Output IP3 tested with two input tones of -20 dBm each with 10 MHz spacing.



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#### **Maximum Operating Conditions**

Parameter	Rating	
Input Power	5 dBm	
IC	120 mA	
Junction Temperature <sup>7,8</sup>	+150°C	
Operating Temperature	-40°C to +105°C	

- 7. Operating at nominal conditions with junction temperature ≤ 130°C will ensure MTTF > 1 x 106 hours.
- Junction Temperature (T<sub>J</sub>) = T<sub>B</sub> + Θjc \* (V \* I)
   Typical thermal resistance (Θic) = 65 °C/W.

a) For  $T_B = +25^{\circ}C$ ,

 $T_J = 55 \, ^{\circ}\text{C} \ @ 5 \, \text{V}, \, 90 \, \text{mA}$ 

b) For  $T_B = +105^{\circ}C$ ,

T<sub>J</sub> = 135 °C @ 5 V, 90 mA

## Absolute Maximum Ratings<sup>9,10</sup>

Parameter	Absolute Maximum	
$V_{DD}$	8 V	
Input Power	20 dBm	
Junction Temperature <sup>11</sup>	+150°C	
Storage Temperature	-65°C to +125°C	

- Exceeding any one or combination of these limits may cause permanent damage to this device
- 10. MACOM does not recommend sustained operation near these survivability limits.
- Junction temperature directly effects device MTTF. Junction temperature should be kept as low as possible to maximize lifetime.

#### **Handling Procedures**

Please observe the following precautions to avoid damage:

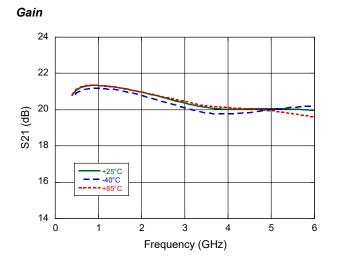
### **Static Sensitivity**

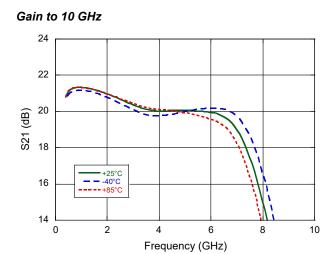
These electronic devices are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these HBM Class 1B devices.



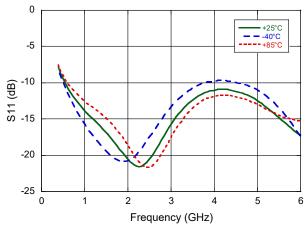
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## Typical Performance Curves @ 5 V / 90 mA, $Z_0$ = 50 $\Omega$ (Probe data with Bias Tees)

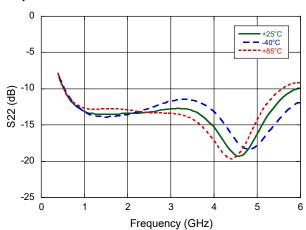




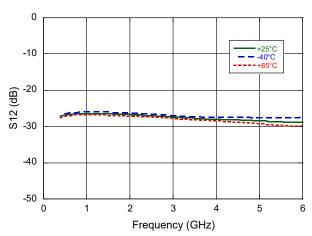
## Input Return Loss



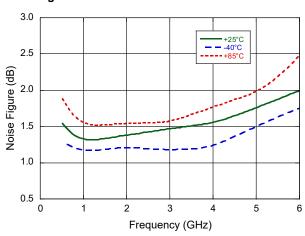
#### **Output Return Loss**



#### Reverse Isolation



#### Noise Figure



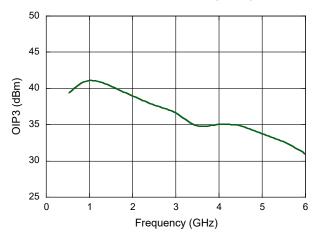
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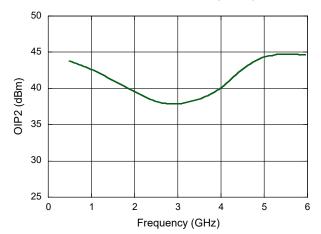
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## Typical Performance Curves @ 5 V / 90 mA, $Z_0$ = 50 $\Omega$ (Probe data with Bias Tees)

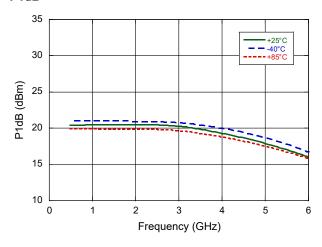
#### OIP3 at $P_{IN}$ = -20 dBm/tone, 10 MHz Spacing



#### OIP2 at P<sub>IN</sub> = -20 dBm/tone, 10 MHz Spacing



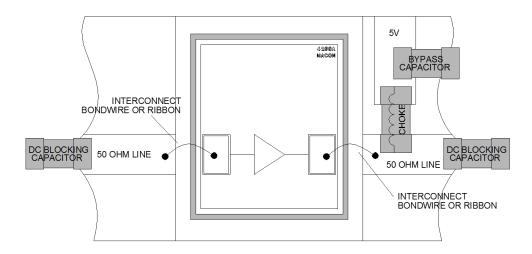
#### P1dB



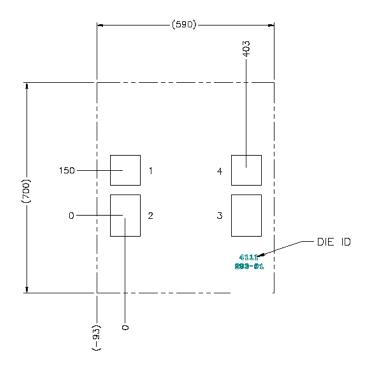


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# Device Assembly<sup>12</sup>



# Die Dimensions<sup>13,14</sup>



## Bond Pad Dimensions (µm)

Pad #	Size		Description	
Pau #	X	Y	Description	
1, 4	100	100	GND	
2	100	139	RF <sub>IN</sub>	
3	100	139	RF <sub>OUT</sub> / V <sub>DD</sub>	

- 12. DO NOT use eutectic (solder) for die attach. Use electrically and thermally conductive epoxy only, such as Ablestick ABP 8062T.
- 13. Dimensions are in microns.
- 14. GND bond pads 1 and 4 are connected to the backside of the die through via holes. These bond pads do not require bond wires. Only pins 2 and 3 require bond wires.

# 21 dB Gain Amplifier, Die 0.4 - 6 GHz



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